NSN 5962-01-363-9437

Memory Microcircuit - Page 1 of 1

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| Operating Tempurature Range: |
|---|
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| End Application: |
| Display conso e/i fscm 49956 |
| Features Provided: |
| Programmed |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Dual-in-line |
| Output Logic Form: |
| Bipolar metal-oxide semiconductor |
| Case Outline Source And Designator: |
| D-2 mil-m-38510 |
| Terminal Surface Treatment: |
| Solder |
| Product Name: |
| Microcircuit, fused msi microcontroller |
| Voltage Rating And Type Per Characteristic: |
| 5.5 volts input |
| Time Rating Per Chacteristic: |
| 40.00 nanoseconds access and 60.00 nanoseconds access |
| Memory Device Type: |
| Prom |
| Test Data Document: |
| 49956-996378-322 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, |
| etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) |
| Terminal Type And Quantity: |
| 16 printed circuit |
| Specification Data: |
| 81349-mil-std-883/tx/ government standard |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| Yes - demil/mli |
| Fiig: |